
HAT2058R/HAT2058RJ

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings		Unit
		HAT2058R	HAT2058RJ	
Drain to source voltage	V _{DSS}	100	100	V
Gate to source voltage	V _{GSS}	±20	±20	V
Drain current	I _D	4	4	A
Drain peak current	I _D (pulse) ^{Note1}	32	32	A
Body-drain diode reverse drain current	I _{DR}	4	4	A
Avalanche current	I _{AP} ^{Note4}	—	4	A
Avalanche energy	E _{AR} ^{Note4}	—	1.6	mJ
Channel dissipation	Pch ^{Note2}	2	2	W
	Pch ^{Note3}	3	3	W
Channel temperature	Tch	150	150	°C
Storage temperature	Tstg	−55 to +150	−55 to +150	°C

- Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%
2. 1 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW ≤ 10 s
3. 2 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW ≤ 10 s
4. Value at Tch = 25°C, Rg ≥ 50 Ω

HAT2058R/HAT2058RJ

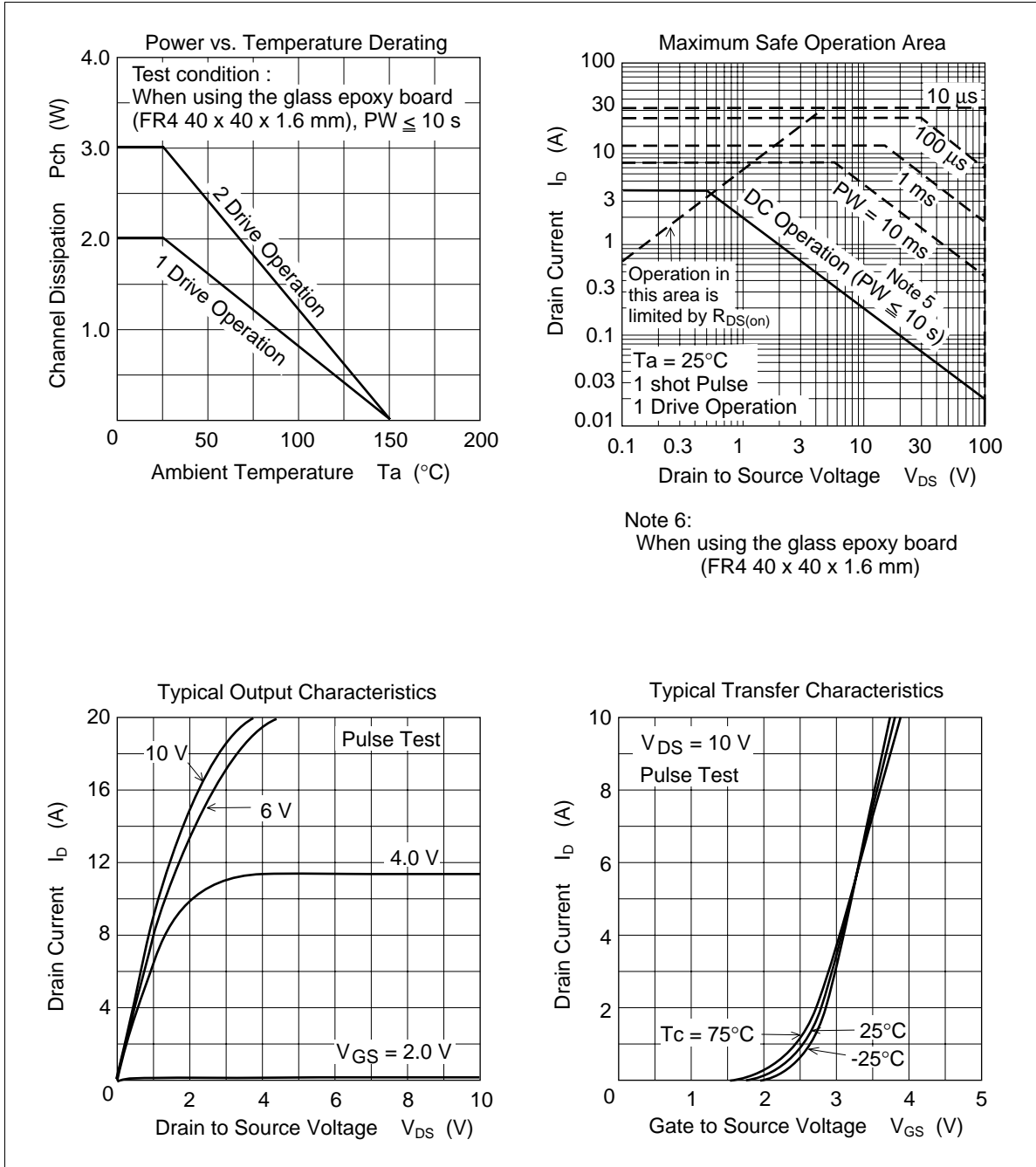
Electrical Characteristics (Ta = 25°C)

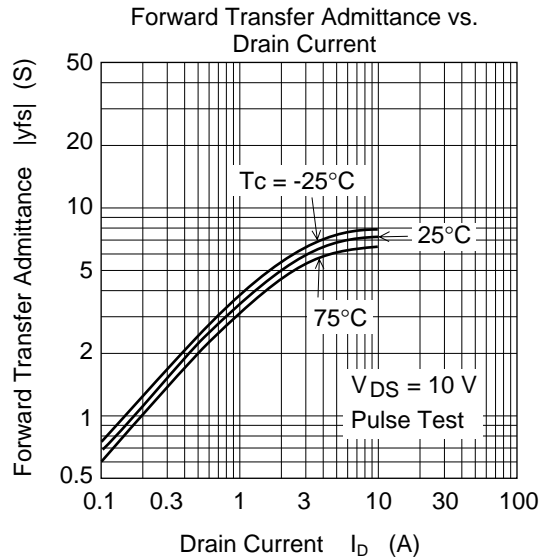
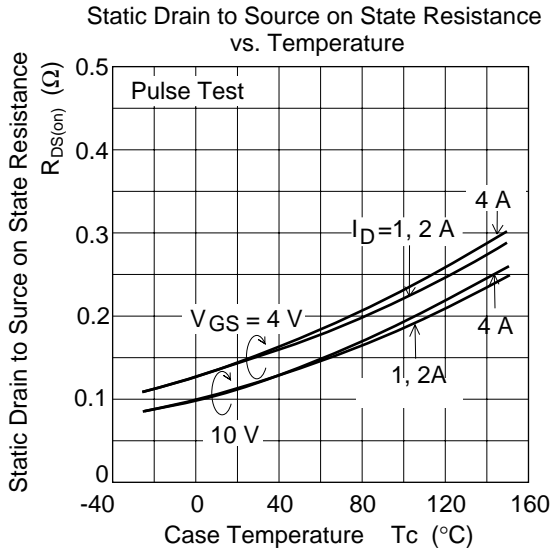
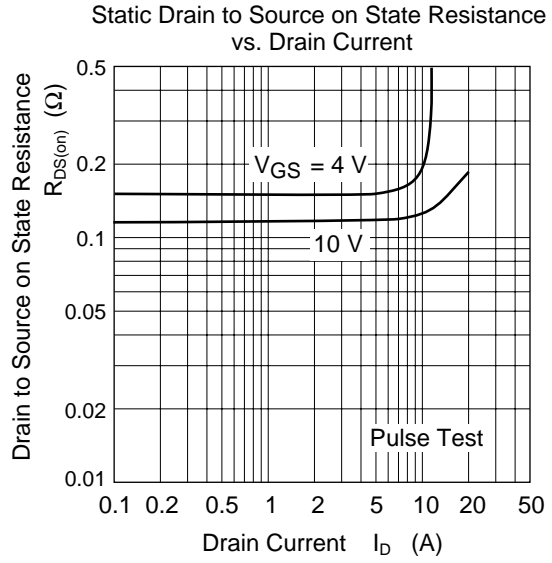
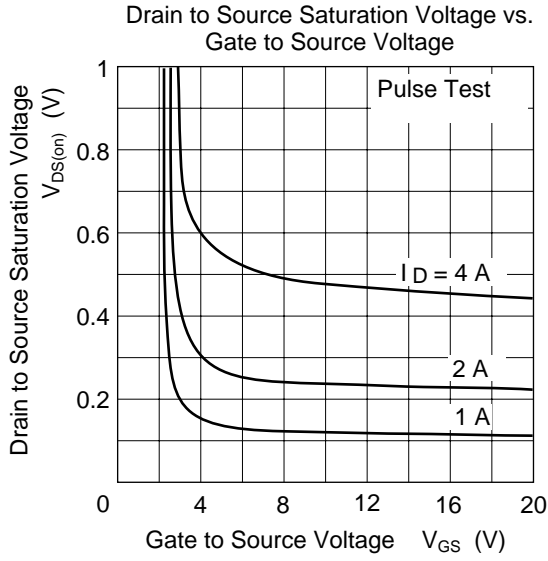
Item	Symbol	Min	Typ	Max	Unit	Test conditions	
Drain to source breakdown voltage	$V_{(BR)DSS}$	100	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 20	—	—	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$	
Zero gate voltage drain current	HAT2058R HAT2058RJ	I_{DSS}	—	—	1 0.1	μA μA	$V_{DS} = 100 \text{ V}, V_{GS} = 0$
Zero gate voltage drain current	HAT2058R HAT2058RJ	I_{DSS}	—	—	—	μA μA	$V_{DS} = 80 \text{ V}, V_{GS} = 0$ $T_a = 125^\circ\text{C}$
Gate to source cutoff voltage	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	
Static drain to source on state resistance	$V_{GS(off)}$	1.0	—	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	
Forward transfer admittance	$ y_{fs} $	3	5	—	S	$I_D = 2 \text{ A}^{*1}, V_{DS} = 10 \text{ V}$	
Static drain to source on state resistance	$R_{DS(on)}$	—	120	145	$\text{m}\Omega$	$I_D = 2 \text{ A}^{*1}, V_{GS} = 10 \text{ V}$	
	$R_{DS(on)}$	—	150	180	$\text{m}\Omega$	$I_D = 2 \text{ A}^{*1}, V_{GS} = 4 \text{ V}$	
Input capacitance	C_{iss}	—	420	—	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$	
Output capacitance	C_{oss}	—	180	—	pF	$f = 1 \text{ MHz}$	
Reverse transfer capacitance	C_{rss}	—	100	—	pF		
Turn-on delay time	$t_d(on)$	—	10	—	ns	$V_{GS} = 10 \text{ V}, I_D = 2 \text{ A}$	
Rise time	t_r	—	30	—	ns	$V_{DD} \cong 30 \text{ V}$	
Turn-off delay time	$t_d(off)$	—	110	—	ns		
Fall time	t_f	—	60	—	ns		
Body-drain diode forward voltage	V_{DF}	—	0.85	1.1	V	$I_F = 4 \text{ A}, V_{GS} = 0^{*1}$	
Body-drain diode reverse recovery time	t_{rr}	—	75	—	ns	$I_F = 4 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$	

Note: 1. Pulse test

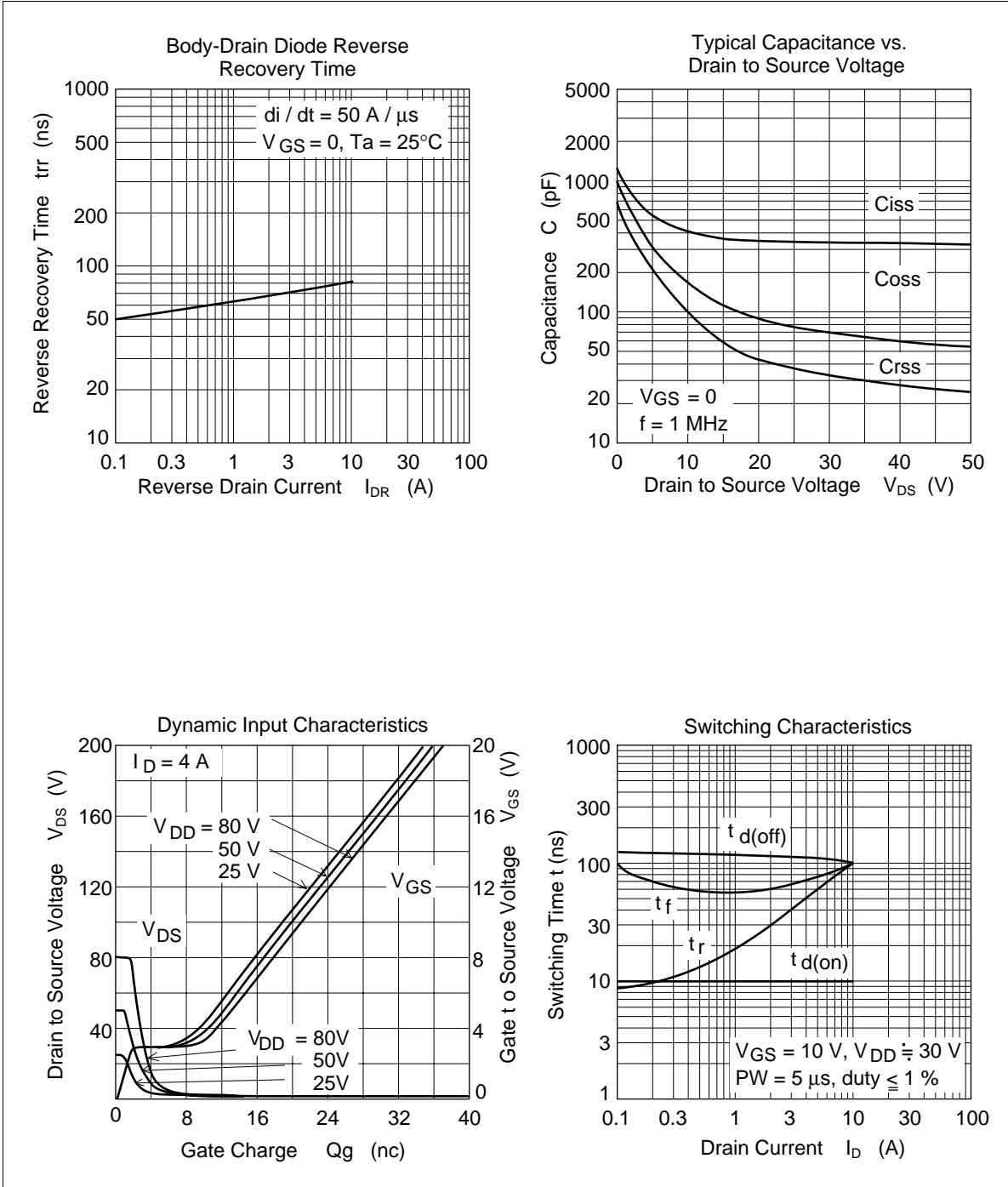
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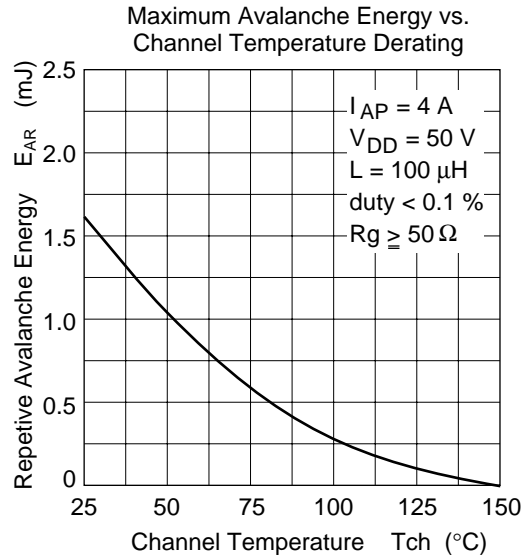
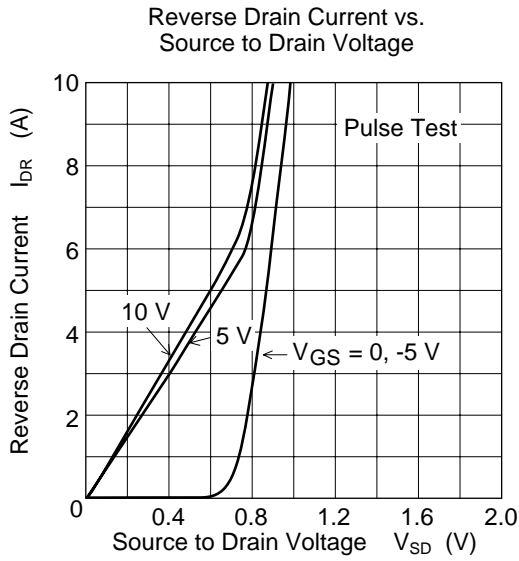
Main Characteristics



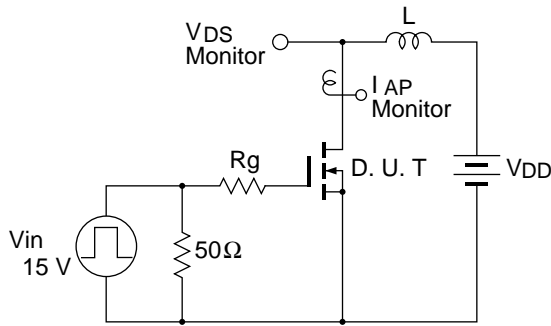


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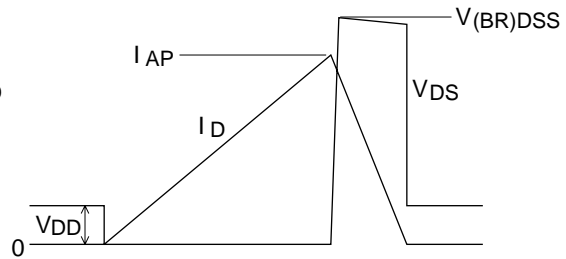


Avalanche Test Circuit

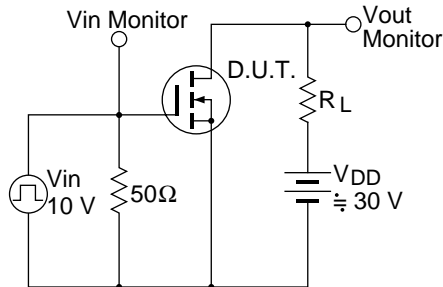


Avalanche Waveform

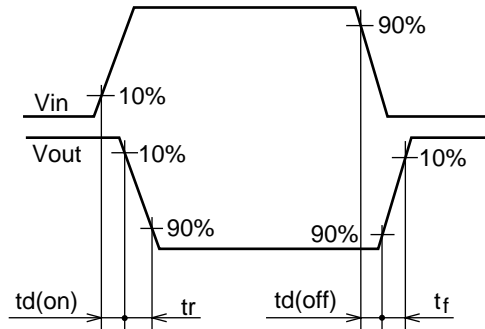
$$E_{AR} = \frac{1}{2} \cdot L \cdot I_{AP}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$$



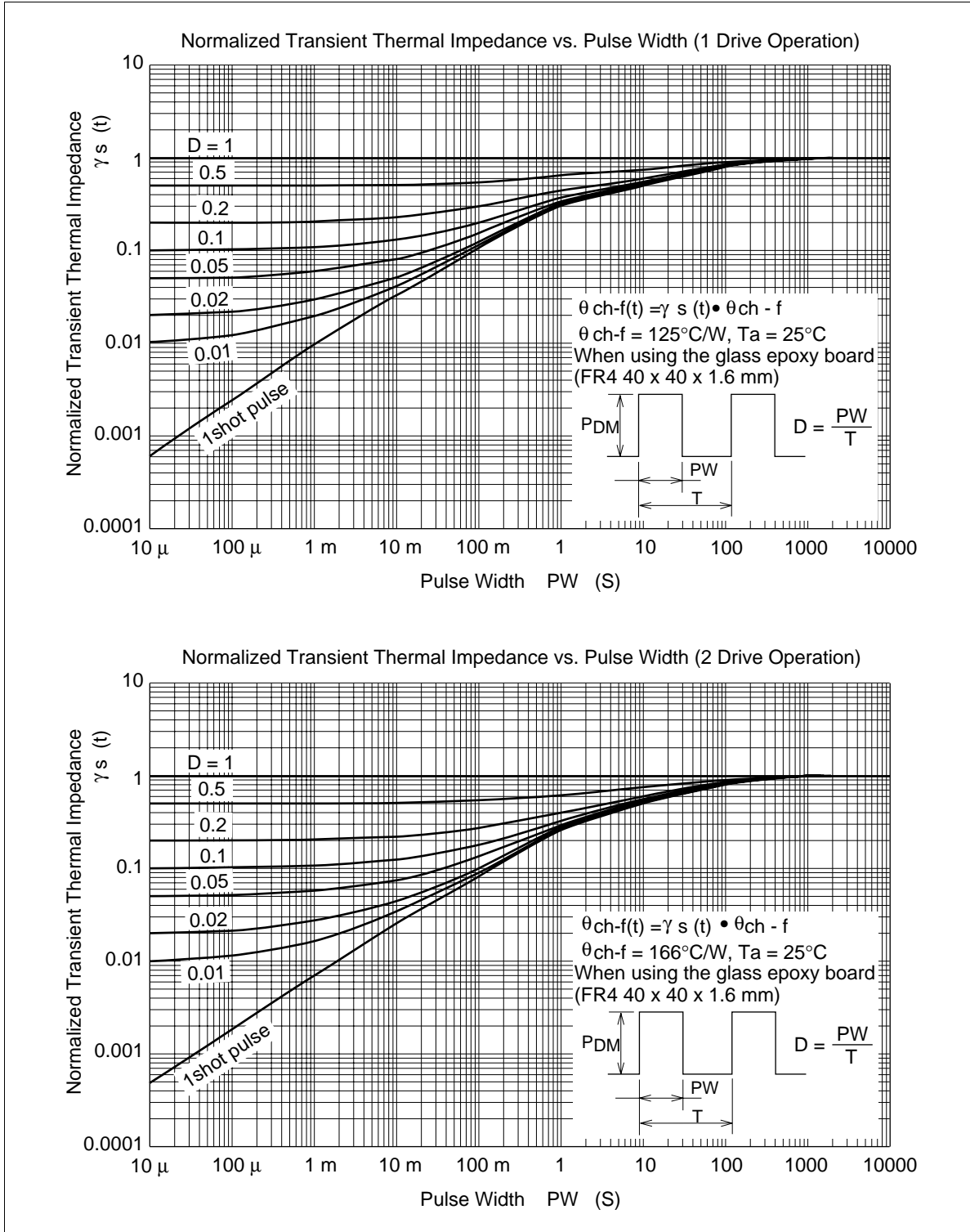
Switching Time Test Circuit



Switching Time Waveform



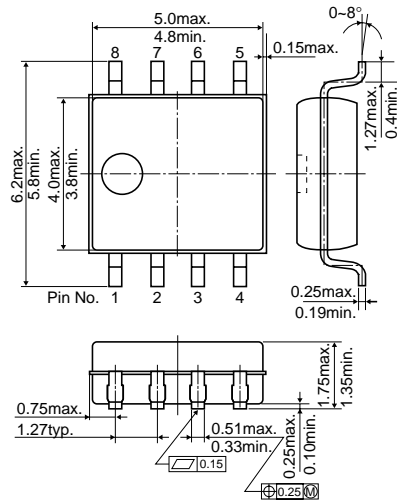
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Package Dimensions

Unit: mm



Hitachi Code	FP-8DA
JEDEC	—
EIAJ	—

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